

📜 Buy Now C2012X6S0G226MT\*\*\*\* TDK item description (2) Commercial Grade PDF file of this page Applications General (Up to 75V) Feature PB PA C2012 [EIA 0805] Series Documents Production (Not Recommended for New Catalog Design) Specification Recommended Alternate Part No. : C2012X7S0J226M125AC (Interchangeability RoHS Certificate SVHC / REACH Certificate

Characterization Sheet

Technical Support Tools

SPICE Netlist (Simple)

SPICE Netlist (Precision)

Equivalent Circuit Model Update

DC Bias / Superimpotision Model (HSpice)

DC Bias / Superimpotision Model (LTSpice)

DC Bias / Superimpotision Model (PSpice) Update

Sample Kits

S-parameter

Status is not guaranteed.) Images are for reference only and show TDK Brand example products.

Size Length(L) 2.00mm ±0.20mm

1.25mm ±0.20mm

0.85mm ±0.15mm

0.20mm Min.

Width(W) 0.50mm Min.

Thickness(T) Terminal Width(B) Terminal Spacing(G)

1.00mm to 1.30mm(Flow Soldering)

Recommended Land Pattern (PA)

0.90mm to 1.20mm(Reflow Soldering)

1.00mm to 1.20mm(Flow Soldering) Recommended Land Pattern (PB)

0.70mm to 0.90mm(Reflow Soldering)

0.80mm to 1.10mm(Flow Soldering)

0.90mm to 1.20mm(Reflow Soldering)

Recommended Land Pattern (PC)

**Electrical Characteristics**  $22\mu F \pm 20\%$ Capacitance

4VDC

X6S(±22%)

Rated Voltage 10%

Temperature Characteristic 2 Dissipation Factor (Max.) Insulation Resistance (Min.) 4ΜΩ

Soldering Method

Package Quantity

AEC-Q200

Packing

Other Wave (Flow)

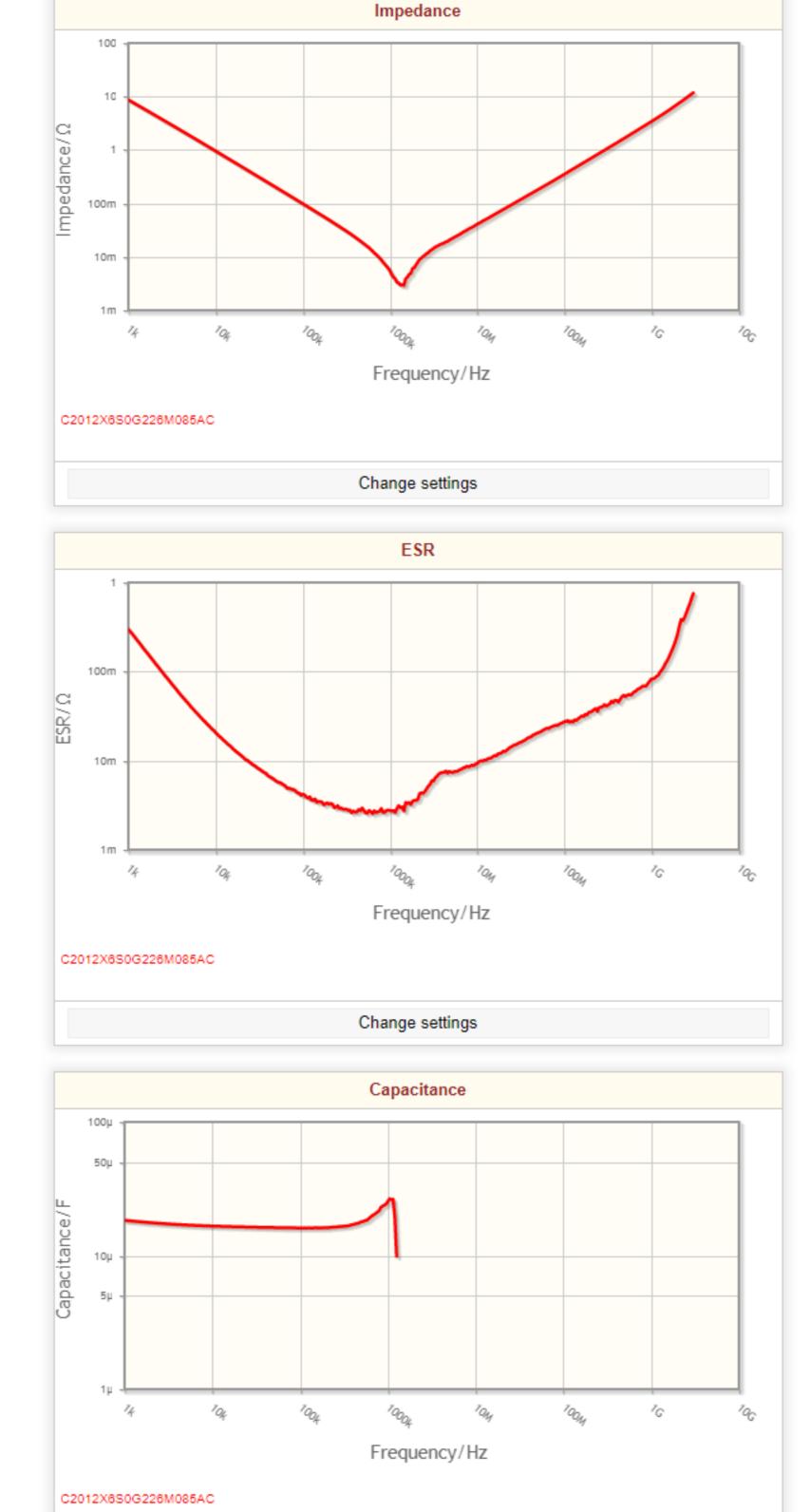
Reflow

4000pcs

Punched (Paper)Taping [180mm Reel]

NO

Characteristic Graph (This is reference data, and does not guarantee the products characteristics.)



Change settings

DC Bias Characteristic

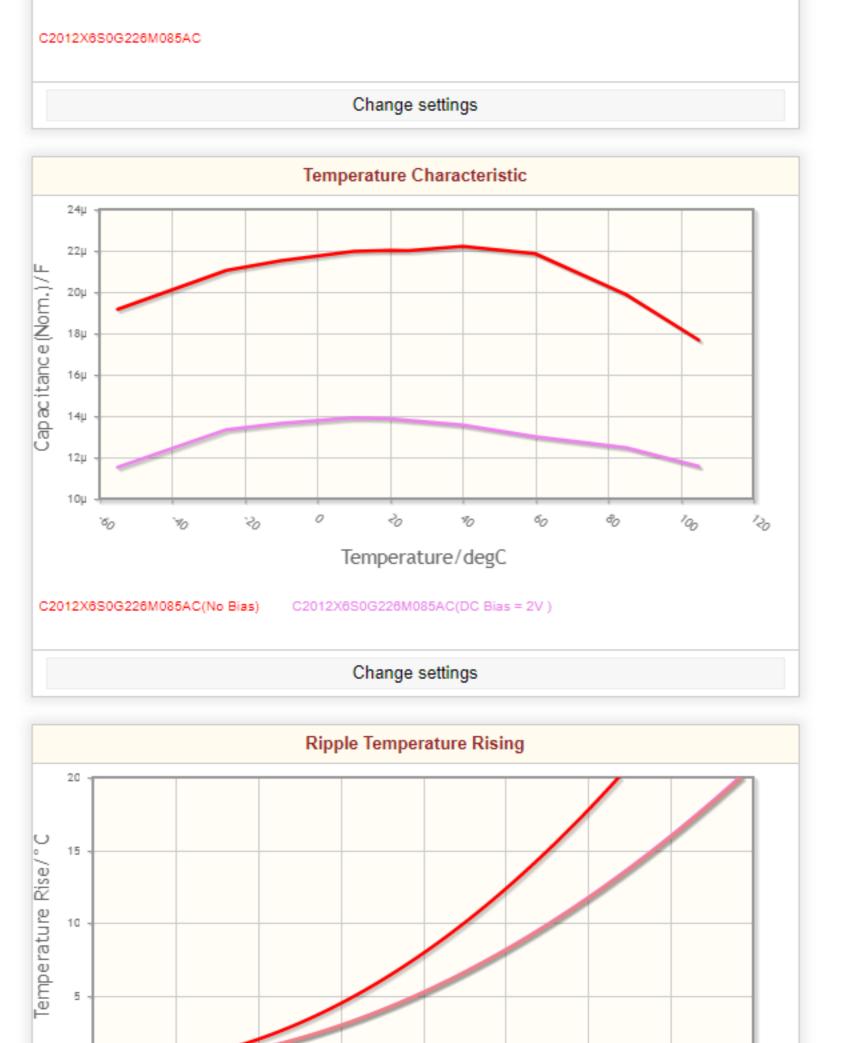
1.5

DC/V

25μ

0.5

Capacitance (Nom.)/F



Ripple Current/Arms

C2012X6S0G226M085AC(500kHz)

Change settings

T.C.=X5R LxWxT:1x0.5x0.5mm General

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C1005X5R0J225M050BC

Capacitance=2.2µF

Edc=6.3V

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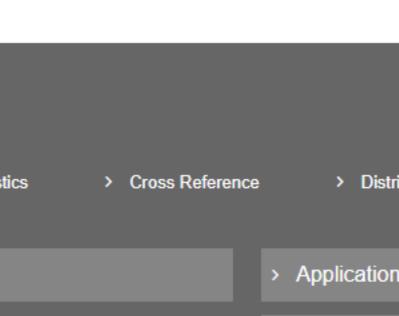
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> FA Systems

Counterfeit Products



C2012X6S0G226M085AC(1MHz)

C1005X7R1C104K050BC

Capacitance=0.1µF

LxWxT:1x0.5x0.5mm

Edc=16V

T.C.=X7R

General

Multilayer Ceramic Chip Capacitors

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